

New Features to Increase the *Thermopower in Magnetic Semiconductors*

Research Article

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Abstract

In this paper thermopower S , magnetothermopower $\Delta S/S$ were studied in single-crystal $\text{Sm}_{1-x}\text{Sr}_x\text{MnO}_3$ ($0.15 \leq x \leq 0.3$). It is known that these compounds consist of f - d ferromagnetic clusters in A-type antiferromagnetic matrix. A sharp increase of S and module of negative $\Delta S/S$ were discovered near Curie temperature T_C , where they achieve giant values. So $|\Delta S/S| = 94.5\%$ in magnetic field 13.23 kOe. This means that thermopower is caused by presence of ferrons, as the value of the thermopower slumps with ferrons' destruction caused by magnetic field or heating over T_C . Therefore thermopower in doped magnetic semiconductors is determined by level of doping and volume of the sample. So after dividing the sample in two parts thermopower of each part decreased proportionally the volume of the sample. Thus, in doped magnetic semiconductors the value of thermopower can be considerably increased by enlarging the volume of sample, the level of doping and can be controlled by magnetic field.

Introduction

Today a practical application of thermoelectricity is considerably constrained because of a low efficiency that depends on S^2 :

$$Z = S^2 / \rho k, \text{ ----- (1)}$$

S is thermopower, ρ – electrical resistivity, k – coefficient of thermal conductivity. In present time there are lots of papers about increasing of Z but unfortunately there is no progress in this field. Increased value of S that was about hundreds of mV was observed in some manganite near Curie temperature [1-3]. Authors explain this value of S by presence of polarons of small radius at Curie temperature. It is known, that polarons of small radius are observed in nonmagnetic semiconductors. Authors of [1-3] do not explain appearance of polarons only at Curie temperature in magnetic semiconductors.

As is well known, interest in magnetic semiconductors was caused by giant magnetoresistance and volume magnetostriction that were observed near Curie temperature [4-6]. Nowadays most of researches explain these effects by presence of special magnetic impurity conditions called ferrons. Theory of ferrons was developed in [7-10]. A donor electron is localized near it because

of the gain in s-d exchange energy and creates around impurity a ferromagnetic region. A crystal lattice is compressed in ferrons [10]. In ferromagnetic semiconductors ferrons exist in Curie temperature region, where long-range ferromagnetic order is partially or completely destroyed and with further heating ferrons are destroyed very rapidly. In antiferromagnetic semiconductors the electron density near impurities is increased, so crystal is antiferromagnetic matrix, deprived of charge carriers, in which symmetrically located ferromagnetic spheres. These spheres are collective ferrons in which the electron density is increased. It must be emphasized that here the notion of Curie temperature is very arbitrarily. It is the temperature of the disruption of ferromagnetic order in the clusters of ferrons type.

Materials and methods

In this paper thermopower S and magnetothermopower $\Delta S/S$ were studied in $\text{Sm}_{1-x}\text{Sr}_x\text{MnO}_3$ ($x=0.15, 0.2, 0.25, 0.3$). The samples are A-type antiferromagnetic SmMnO_3 doped by Sr. Single-crystalline samples were grown using crucibleless floating zone melting. A temperature gradient of 5 K across the sample for the thermopower and magnetothermopower measurements was created using the electrical furnace on one end of the sample. Three copper-constantan thermocouples were used: to measure

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temperature difference between hot and cold ends of the sample and temperature at the middle of the sample. Measurements of thermopower were carried out by analog-to-digital converter NI-9211 allowing to measure small value of voltage with the relative measurement error 0.05% and input resistance 20M Ω . The electric resistivity and magnetoresistance were also studied on this complex.

The magnetization of the sample was measured with SQUID magnetometer. By studying data of neutron and electron diffraction in [11-15] it was found that compounds with $x < 0.33$ consist of ferron-type ferromagnetic clusters, arranged in A-type antiferromagnetic matrix.

Results and Discussion

Figure 1 shows the temperature dependence of the magnetization $M(T)$ in different magnetic fields of composition with $x = 0.3$. It's seen that the transition from ferromagnetic to paramagnetic state is heavily blurred. It follows that it is a magnetically heterogeneous sample. The Curie temperature of this sample T_C

$= 87$ K is defined as the temperature of minimum on $dM(T)/dT$ curve, measured in magnetic field 0.1 kOe. It should be noted that the concept of the Curie temperature here is very conditional: it is the Curie temperature of the ferromagnetic clusters (ferrons). Similar magnetization measurements were carried out on samples with $x = 0.15, 0.2, 0.25$. $M(T)$ curves of these samples are very similar to observed one in the composition with $x = 0.3$. Their Curie temperatures are close to $T_C = 87$ K of the composition with $x = 0.3$. They are presented in table and almost coincide with data given in [14].

Figure 2 shows the temperature dependence of thermopower $S(T)$ in different magnetic fields in the sample with $x = 0.3$ and geometric dimensions 11 mm x 2.5 mm x 3 mm. This figure shows that the thermopower reaches a giant value of 18 mV/K in the area of $T_C = 87$ K, and decreases rapidly above this temperature. Figure 3 shows the temperature dependence of magneto thermopower $\{\Delta S/S\}(T)$ for this sample in different magnetic fields. It's clear that magneto thermopower is negative and its absolute value near T_C reaches a giant value of 94.5% in a magnetic field 13.23 kOe. A similar behavior of the thermopower

Figure 1. Temperature dependence of the magnetization $M(T)$ in different magnetic fields for the compound with $x = 0.3$.

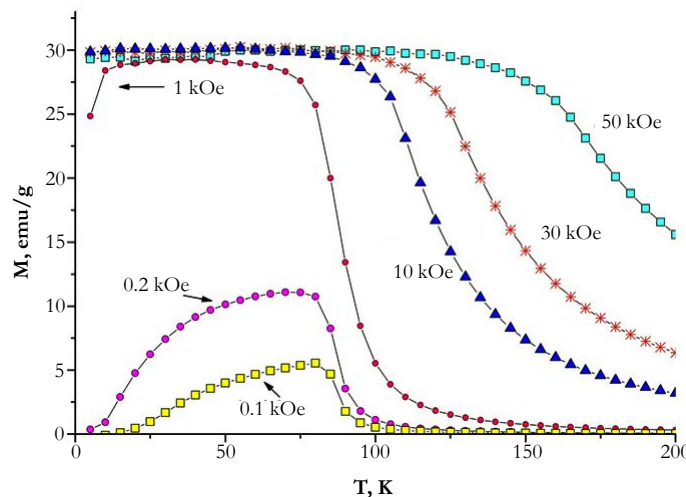


Figure 2. Temperature dependence of the thermopower $S(T)$ in different magnetic fields for the compound with $x = 0.3$ and geometrical dimensions 11 mm x 2.5 mm x 3 mm.

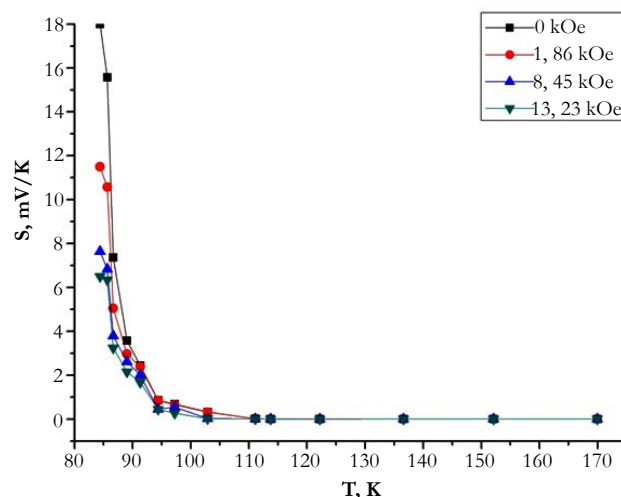


Figure 3. Temperature dependence of the magnetothermopower $\{\Delta S/S\}(T)$ in different magnetic fields for the compound with $x = 0.3$.

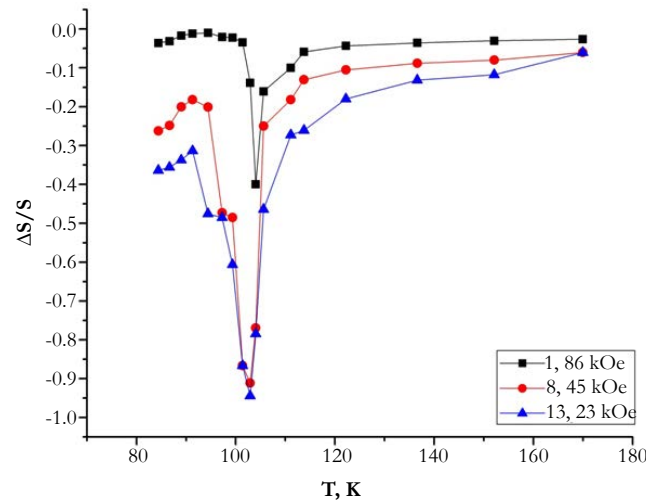
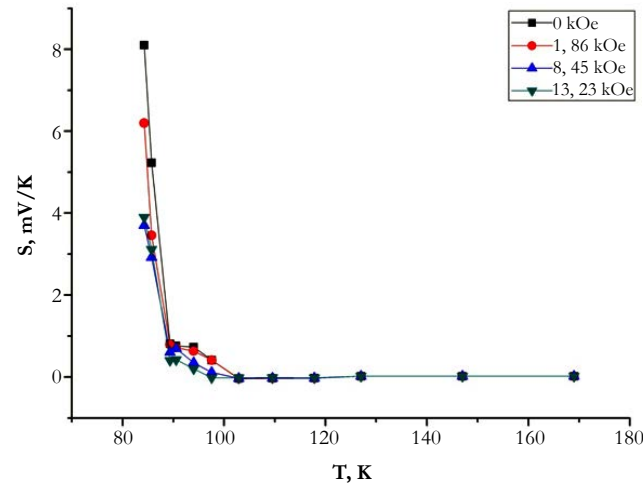


Table 1. The Curie temperature T_c and maximum values of thermopower S , magnetothermopower $\Delta S/S$, resistivity ρ , magneto-resistivity $\Delta\rho/\rho$ at the Curie temperature depending on the concentration x .

x	T_c, K	$S, mV/Kmm^3$	$\Delta S/S$	$\rho \text{ Ohm}\cdot m$	$\Delta\rho/\rho$
0.15	80	0.525	-0.54	1683	-0.7
0.2	90	0.575	-0.37	2083	-0.33
0.25	95	0.9	-0.64	2599	-0.51
0.3	87	0.21	-0.94	677	-0.76

Figure 4. Temperature dependence of the thermopower $S(T)$ in different magnetic fields for the compound with $x = 0.3$ and geometrical dimensions 5 mmx 2.5 mmx 3 mm, obtained by a division of the sample, that details are shown in Figure. 2.



and magnetothermopower was observed in compositions with $x = 0.15, 0.2, 0.25$. Maximum values of S and $|\Delta S/S|$ were observed near T_c and presented in Table 1, which shows that in all studied samples quantities of maxima reach giant values. Figure 5 and Figure 6 show the temperature dependences of resistivity ρ and magneto resistance $\Delta\rho/\rho$ of sample with $x = 0.3$ which are typical of samples with $x = 0.15, 0.2, 0.25$. All of compositions near the Curie temperature have a giant increase of the resistivity ρ and the absolute value of negative magneto resistance $\Delta\rho/\rho$, typical for doped magnetic semiconductors, which most of the researchers explain by the existence of impurity ferrons. Maximum values of ρ and $\Delta\rho/\rho$ in all studied samples are shown in Table 1. It should be noted that curves $\rho(T)$ and $S(T)$ and $\Delta\rho/\rho(T)$ and $\Delta S/S\{T\}$ have similar behavior. This indicates that they are caused by the

same reason - the existence of ferrons.

The presence of giant thermopower and negative magnetothermopower detected in the manganite compounds means that thermoelectric power in it is mainly caused by ferrons, as thermopower sharply decreases with the thermal destruction of ferrons or destruction of its by a magnetic field. This is confirmed by the following experience. Figure 4 shows the temperature dependence of the thermopower in different magnetic fields for 5 mm x 2.5 mm x 3 mm sample with $x = 0.3$, obtained after cutting the sample which data was shown on Figure 2. It is seen that a decrease of volume in 2.2 times cases reduction of the thermopower in 2.2 times from 18 mV/K to 8.1 mV/ K. This means that the thermopower must be specified

Figure 5. Temperature dependence of the $\rho(T)$ in different magnetic fields for the compound with $x= 0.3$.

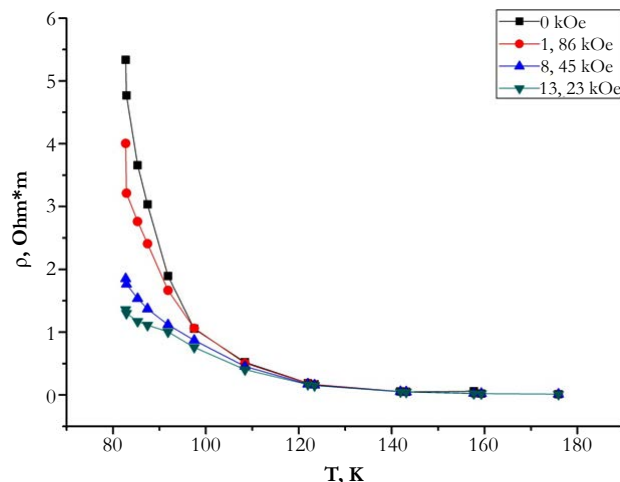


Figure 6. Temperature dependence of the $\{\Delta\rho/\rho\} (T)$ in different magnetic fields for the compound with $x= 0.3$ with $x= 0.3$.

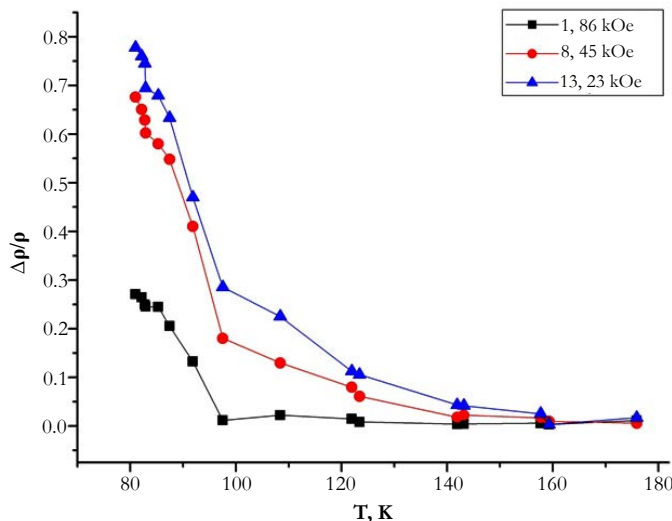
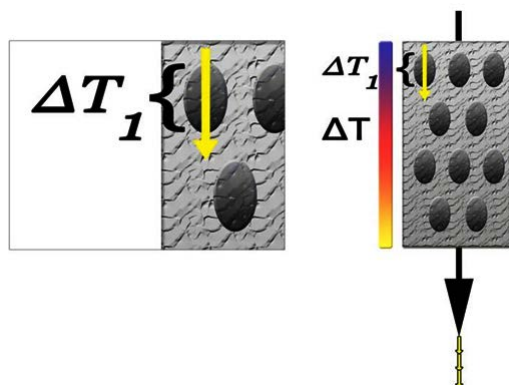


Figure 7. The scheme of a magnetic semiconductor sample with nanoclusters of ferron type in the measurement of the thermopower



per unit volume to compare the thermopower in different compounds, i.e., indicate the specific thermopower Maximum values of S and $|\Delta S/S|$ were observed near T_c and presented in Table 1, which shows that in all studied samples quantities of maxima reach giant values. However, as can be seen from Table1, the value of the specific thermoelectric power increases with the impurity concentration up to $x = 0.3$ at which it decreases, but still remains a very large. Apparently in the composition with x

$=0.3$ begin to appear antiferromagnetic clusters with CE-type antiferromagnetic ordering, in which there is a charge-orbital ordering These new clusters to partially displace ferrons and lower thermopower sample. It is known that in compounds with $0.4 \leq x \leq 0.5$ these clusters occupy a large part of the sample [11, 12]. Thus, the magnitude of the thermoelectric power can be greatly increased by enlarging of the volume of the sample. As known, in nonmagnetic semiconductors thermopower does not depend

on the sample's volume. As is shown in Figure 7, thermopower S_j appears on every single ferron under the influence of local temperature gradient ΔT_l , made from total temperature gradient ΔT . Each of these microregions makes a contribution ($S_j - S_2$) in the thermopower of the whole sample, here S_2 – thermopower of antiferromagnetic matrix in the absence of ferrons. So, ferrons' contribution affect the efficient value S of the whole sample. Hence, it follows that the thermopower in doped magnetic semiconductor is determined by of the doping concentration and the volume of the sample. Due to the implementation of the law of conservation of energy, we can assume that the gradients ΔT_l on ferrons created by lowering the coefficient of thermal conductivity. It is well known that phonons become more anharmonic with the increase of weight of atoms or atomic groups that form the crystal. This increased anharmonicity leads to lower coefficient of thermal conductivity. Ferrons are one of such groups because in ferrons lattice is compressed. Thus, the presence of impurity ferrons in the magnetic semiconductor causes a sharp increase of the thermopower in it and reduces the coefficient of thermal conductivity, which, according to equation (1), leads to increasing of efficiency. Thus, the magnitude of the thermoelectric power can be greatly increased by enlarging of the volume of the sample. As known, in nonmagnetic semiconductors thermopower does not depend on the sample's volume.

Thus, in doped magnetic semiconductors, which include manganites, the value of thermopower can be significantly increased, in comparison with undoped one, by increasing the concentration of impurities and the volume of the sample. In addition the value of thermopower can be controlled by the magnetic field.

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